# INTERNATIONAL STANDARD

# ISO/IEC 10373-6

Fourth edition 2020-07 **AMENDMENT 1** 2021-05

# Cards and security devices for personal identification — Test methods —

Part 6: Contactless proximity objects

# iTeh STAMENDMENTRE Dynamic power level (stmanagement.ai)

Cartes et dispositifs de sécurité pour l'identification personnelle — ISC/FF 165/34F2020/And 12021 https://standards.iteh.avcatalog/standards/sist/b9a7097b-9c6a-4c66-897f-00dae59f Partie 6: Objets sans contact de proximité

AMENDEMENT 1: Gestion dynamique de niveau de puissance



Reference number ISO/IEC 10373-6:2020/Amd.1:2021(E)

# iTeh STANDARD PREVIEW (standards.iteh.ai)

<u>ISO/IEC 10373-6:2020/Amd 1:2021</u> https://standards.iteh.ai/catalog/standards/sist/b9a7097b-9c6a-4c66-897f-00dae59fld78/iso-iec-10373-6-2020-amd-1-2021



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This document was prepared by Joint Technical Committee ISO/IEC JTC 1, Information technology, Subcommittee SC 17, Cards and security devices for personal identification.

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# Cards and security devices for personal identification — Test methods —

# Part 6: Contactless proximity objects

# AMENDMENT 1: Dynamic power level management

Page 3, 3.2

Add the following symbols:

"*H*<sub>0</sub> PCD field strength during power level management test procedures"

#### Page 7, 4.7, Table 3

# Add the following two rows after the row for "Optional PICC classes": " (standards.iteh.ai)

	Description 73-6:2020/Amd 1:2021	Unit
https://standards Support of PLI <sub>ATQ</sub> handling 00da	Ability to change power level (and therefore field strength) after re- ceiving PLI <sub>ATO</sub> from a PICC <sup>0-</sup> and 1-2021	
Support of PLI <sub>CID</sub> handling	Ability to change power level (and therefore field strength) after receiving $\mbox{PLI}_{\mbox{CID}}$ from a PICC	

"

Page 8, 4.8, Table 6

Replace Table 6 with the following table:

..

#### Table 6 — PICC manufacturer information

Parameter	Description	Unit
Location, center and size of the antenna	Drawing with dimensions of the PICC outside shape and the posi- tion of the external rectangle/circle of the claimed PICC class.	
PICC class (optional) <sup>a</sup>	Claimed PICC class	
Resonance frequency range (op- tional)	Minimum and maximum resonance frequency	MHz
Communication signal interface	Supported communication signal interface(s): — Type A — Type B — Type A and Type B	
<sup>a</sup> If not provided, test methods for	Class 1 shall be used	·

Parameter	Description	Unit
Temperature range	Minimum and maximum temperature values	°C
Supported PLI <sub>ATQ</sub> values	List of supported optional PLI <sub>ATQ</sub> values in Answer to Request	
Supported PLI <sub>CID</sub> values	List of supported optional PLI <sub>CID</sub> values in CID field	
PCD to PICC supported bit rates	List of supported optional PCD to PICC bit rates	
PICC to PCD supported bit rates	List of supported optional PICC to PCD bit rates	
Same bit rate for both directions	Indication if only same bit rate from PCD to PICC and from PICC to PCD is supported	
Random or fixed UID (Type A) or PUPI (Type B)	Indication whether the UID (Type A) or PUPI (Type B) is random or fixed	
Maximum frame size supported	Maximum frame size in reception	byte
PCD to PICC frame with error cor- rection supported	Frame with error correction from PCD to PICC	
PICC to PCD frame with error cor- rection supported	Frame with error correction from PICC to PCD	
TEST_COMMAND_SEQUENCE1	See 0.2.1	
TEST_COMMAND1	See 0.2.1	
TEST_COMMAND2	See 0.2.1	
TEST_COMMAND3	See 0.2.1	
TEST_COMMAND4	See 0.2.1 ANDARD PREVIEW	
<sup>a</sup> If not provided, test methods for	Class 1 shall be used	

#### Table 6 (continued)

...

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#### Page 38, 7.1.9

Add the following subclause after 7.1.8.3:

#### "

#### 7.1.9 Procedures for PCD supporting optional $PLI_{ATQ}$ or $PLI_{CID}$ handling

#### 7.1.9.1 Scope

These tests apply only to PCDs which support  ${\rm PLI}_{\rm ATO}$  or  ${\rm PLI}_{\rm CID}$  handling.

If the PCD supports optional  $PLI_{ATQ}$  or  $PLI_{CID}$  handling, the additional procedures specified in 7.1.9.2, 7.1.9.3, 7.1.9.4 and H.5 shall be used to verify that, for every power level used by the PCD:

- a) the PCD complies with the field strength requirements specified in ISO/IEC 14443-2:2020/Amd 1, ISO/IEC 14443-3:2018/Amd 1 and ISO/IEC 14443-4:2018/Amd 1;
- b) the PCD complies with modulation index and waveform requirements specified in ISO/IEC 14443-2;
- c) the PCD complies with load modulation reception requirements specified in ISO/IEC 14443-2;
- d) the PCD complies with EMD immunity requirements specified in ISO/IEC 14443-2.

#### 7.1.9.2 Modulation index and waveform

The steps c) to g) of the procedure specified in 7.1.4.2 shall be repeated for every power level between minimum and maximum power level obtained by  $PLI_{ATO}$  or  $PLI_{CID}$ .

For each power level, the test report shall be as specified in 7.1.4.3.

#### 7.1.9.3 Load modulation reception

The procedures specified in 7.1.6.5 and 7.1.6.6 shall be repeated for every power level between minimum and maximum power level obtained by  $PLI_{ATO}$  or  $PLI_{CID}$ .

For each power level, the test report shall be as specified in 7.1.6.7.

#### 7.1.9.4 PCD EMD immunity test

The steps b) to l) of the procedure specified in 7.1.8.2 shall be repeated for every power level between minimum and maximum power level obtained by  $PLI_{ATO}$  or  $PLI_{CID}$ .

For each power level, the test report shall be as specified in 7.1.8.3.

"

Page 38, 7.2.1.1

Replace the text with the following:

"The purpose of this test is to verify that the load modulation amplitude  $V_{\rm LMA}$  of the PICC and the phase parameters  $\mathcal{O}_{\rm LM,\ INTER}$  and  $\mathcal{O}_{\rm LM,\ INTER}$  of the PICC conform to ISO/IEC 14443-2 for all mandatory and supported optional PICC to PCD bit rates within the operating field range  $[H_{\rm min}$  respectively  $H_{\rm LP}$  if the PICC supports  ${\rm PLI}_{\rm ATO}$  or  ${\rm PLI}_{\rm CID}$ ,  $H_{\rm max}$ ]."

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Page 40, 7.2.2.1

Replace the text with the following: <u>O/IEC 10373-6:2020/Amd 1:2021</u>

"The purpose of this test is to determine that the PICC does not generate an electromagnetic disturbance amplitude  $V_{\rm EMD}$  higher than  $V_{\rm E, PICC}$  during  $t_{\rm E, PICC}$  with the exceptions defined in ISO/IEC 14443-2 within the operating field range [ $H_{\rm min}$  respectively  $H_{\rm LP}$  if the PICC supports PLI<sub>ATQ</sub> or PLI<sub>CID</sub>,  $H_{\rm max}$ ] as specified in ISO/IEC 14443-2 for all supported PICC to PCD bit rates.

NOTE 1 The low EMD time  $t_{E, PICC}$  is a function of FDT/TR0 as defined in ISO/IEC 14443-3:2018, 8.2.

NOTE 2 The EMD limit  $V_{\text{E, PICC}}$  is a function of the field strength.

"

Page 41, 7.2.3.1

Replace the text with the following:

"The purpose of this test is to verify the ability of the PICC to receive the PCD commands within the operating field range  $[H_{\min}$  respectively  $H_{LP}$  if the PICC supports  $PLI_{ATQ}$  or  $PLI_{CID}$ ,  $H_{\max}$ ] as specified in ISO/IEC 14443-2 for all supported PCD to PICC bit rates."

Page 45, 7.2.5.1

Replace the text with the following:

"This test is used to measure the PICC loading effect at the minimum operating field strength  $H_{\min}$  respectively  $H_{\text{LP}}$  if the PICC supports  $\text{PLI}_{\text{ATO}}$  or  $\text{PLI}_{\text{CID}}$  as specified in ISO/IEC 14443-2."

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#### Page 45, 7.2.5.2

Add the following paragraph after the 3<sup>rd</sup> paragraph:

"If the PICC supports  $PLI_{ATQ}$  or  $PLI_{CID}$ , the test shall be repeated at a field strength of  $H_{LP}$ , with the Reference PICC having R2 value, or alternatively the applied voltage on CON2, set for a field strength of  $H_{LP}$ ."

Page 46, 7.2.6.1

Replace the text with the following:

"This test verifies that the PICC operates as intended within the operating field range  $[H_{\min}$  respectively  $H_{LP}$  if the PICC supports  $PLI_{ATQ}$  or  $PLI_{CID}$ ,  $H_{\max}$ ] as specified in ISO/IEC 14443-2 for all supported PCD to PICC bit rates."

Page 47, 7.2.7

Add the following subclause after 7.2.6.4:

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# 7.2.7 Procedures for PICC supporting optional PLI<sub>ATO</sub> or PLI<sub>CID</sub> values

#### 7.2.7.1 Scope

These tests apply only to PICCs which support PLIATO or PLICD values.

If the PICC supports optional  $PLI_{ATQ}$  or  $PLI_{CID}$  values, the additional procedures specified in 7.2.1, 7.2.2, 7.2.3, 7.2.5 and 7.2.6 and the additional procedures specified in 7.2.7.2 to 7.2.7.4 shall be used to verify that:

- a) the PICC complies with the requirements specified in ISO/IEC 14443-2:2020/Amd 1, ISO/IEC 14443-3:2018/Amd 1 and ISO/IEC 14443-4:2018/Amd 1;
- b) the PICC complies with the transmission requirements specified in ISO/IEC 14443-2 for a field strength of  $H_{\rm LP}$ ;
- c) the PICC complies with the EMD level and low EMD time requirements specified in ISO/IEC 14443-2 and ISO/IEC 14443-3 for a field strength of  $H_{\rm LP}$ ;
- d) the PICC complies with the reception requirements specified in ISO/IEC 14443-2 for a field strength of  $H_{\rm LP}$ ;
- e) the PICC complies with the maximum loading effect requirements specified in 7.2.5 for a field strength of  $H_{\rm LP}$ ;
- f) the PICC complies with operating field strength requirements specified in 7.2.6 for a field strength of  $H_{\rm LP}$ .

#### 7.2.7.2 Determination of PICC minimum requested field strength $H_{LP}$

The following sequence is applied to determine the minimum field strength  $H_{LP}$  that the PICC may request and at which it shall comply with all ISO/IEC 14443 requirements.

a) Find the minimum field strength at which the PICC still indicates that its received field strength is at least ( $H_{LP} + H_{step, max}$ ), with a resolution of 0,1 dB (a factor of ~1,012).  $H_{step, max}$  is specified in ISO/IEC 14443-2:2020/Amd 1:2021, 6.3.

NOTE This can be achieved by decreasing the Test PCD assembly field strength by steps of 0,1 dB while the PICC indicates its received field strength is at least ( $H_{LP} + H_{step, max}$ ) or by using a dichotomic search.

b) Obtain  $H_{\text{LP}}$  by subtracting  $H_{\text{step, max}}$  to the minimum field strength at which the PICC still indicates that its received field strength is at least  $(H_{\text{LP}} + H_{\text{step, max}})$ .

#### 7.2.7.3 Maximum field strength change test using PLI<sub>ATO</sub>

#### 7.2.7.3.1 General

This subclause verifies PICC operation after worst case field strength steps following  $PLI_{ATO}$  indication.

#### 7.2.7.3.2 Procedure

Perform the following steps for single step up:

- a) Adjust the RF power delivered by the signal generator to the Test PCD antenna to produce the PICC minimum requested field strength  $H_{\rm LP}$  as measured by the calibration coil.
- b) Place the PICC under test into the DUT position. The RF drive into the Test PCD antenna shall be readjusted to the required field strength if necessary.
- c) Send a REQA for PICC Type A or a REQB(AFI, N=1) for PICC Type B.
- d) If PLI<sub>ATQ</sub> in the PICC response is not (00)b then send a step increase of H<sub>step, max</sub> to the Test PCD assembly power amplifier to set the Test PCD assembly field strength with minimum achievable rise/fall time.
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- e) Immediately after a guard time of  $t_{\rm PP}$  (as specified in ISO/IEC 14443-3:2018/Amd 1:2021, 6.5.2.3), send start of communication or SOF of the next anticollision command, AC for PICC Type A or ATTRIB(PUPI) for PICC Type B.

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- f) Check that the PICC response is as expected rds/sist/b9a7097b-9c6a-4c66-897f-
- g) Put the PICC in IDLE state by sending a REQA for PICC Type A or a DESELECT and a WUPB(nAFI) for PICC Type B.

NOTE 1 If the PICC Type B is not compliant with ISO/IEC 14443-4, then commands used in steps e) and g) can be modified, e.g. using HLTB(PUPI) in step e) and WUPB(nAFI) in step g).

h) Repeat steps c) to g) until the Test PCD assembly field strength is  $H_{\text{max}}$ , using a smaller value for the last step increase if necessary, or until PLI<sub>ATO</sub> is (00)b at step d).

Perform the following steps for single step down:

- i) Adjust the RF power delivered by the signal generator to the Test PCD antenna to produce the PICC maximum field strength  $H_{max}$  as measured by the calibration coil.
- j) Send a REQA for PICC Type A or a REQB(AFI, N=1) for PICC Type B.
- k) If PLI<sub>ATQ</sub> is (11)b then send a step decrease of *H*<sub>step, max</sub> to the Test PCD assembly power amplifier to set the Test PCD assembly field strength with minimum achievable rise/fall time.
- l) Immediately after a guard time of  $t_{PL}$ , send start of communication or SOF of the next anticollision command, AC for PICC Type A or ATTRIB(PUPI) for PICC Type B.
- m) Check that the PICC response is as expected.
- n) Put the PICC in IDLE state by sending a REQA for PICC Type A or a DESELECT and a WUPB(nAFI) for PICC Type B.

NOTE 2 If the PICC Type B is not compliant with ISO/IEC 14443-4, then commands used in steps l) and n) can be modified, e.g. using HLTB(PUPI) in step l) and WUPB(nAFI) in step n).

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o) Repeat steps j) to n) until PLI<sub>ATO</sub> is not (11)b at step k).

Perform the following steps for multiple step up:

- p) Adjust the RF power delivered by the signal generator to the Test PCD antenna to produce the PICC minimum requested field strength  $H_{\rm LP}$  as measured by the calibration coil.
- q) Send a REQA for PICC Type A or a REQB(AFI, N=1) for PICC Type B.
- r) If  $PLI_{ATQ}$  is not (00)b then send several consecutive steps increase of  $H_{step, max}$  to the Test PCD assembly power amplifier to set the Test PCD assembly field strength with minimum achievable rise/fall time, each step increase being followed by a guard time of  $t_{PL}$ , up to a field strength of  $H_{max}$  as measured by the calibration coil.

NOTE 3 The last step increase can have a smaller value to reach exactly  $H_{\text{max}}$ .

- s) Immediately after the last guard time of  $t_{PL}$ , send start of communication or SOF of the next anticollision command, AC for PICC Type A or ATTRIB(PUPI) for PICC Type B.
- t) Check that the PICC response is as expected.

NOTE 4 In any step of this procedure,  $t_{\rm PL}$  can be set to a non-default value by  ${\rm PLI}_{\rm ATQ}$ . This new current value applies until a subsequent setting or until the end of the procedure as the PICC is never reset to POWER-OFF state during the procedure.

#### 7.2.7.3.3 Test report

The test is PASS if the PICC response in steps f), m) and t) is as expected, otherwise the test is FAIL.

### 7.2.7.4 Maximum field strength change test using PLicmteh.ai)

#### 7.2.7.4.1 General

ISO/IEC 10373-6:2020/Amd 1:2021

This subclause verifies PICC operation after worst case field strength steps following PLI<sub>CID</sub> indication.

#### 7.2.7.4.2 Procedure

Perform the following steps for single step up:

- a) Adjust the RF power delivered by the signal generator to the Test PCD antenna to produce the PICC minimum requested field strength  $H_{\rm LP}$  as measured by the calibration coil.
- b) Place the PICC under test into the DUT position. The RF drive into the Test PCD antenna shall be readjusted to the required field strength if necessary.
- c) Put the PICC in PROTOCOL state and initiate a first I-block exchange.
- d) If  $PLI_{CID}$  in the PICC response is not (00)b then send a step increase of  $H_{step, max}$  to the Test PCD assembly power amplifier to set the Test PCD assembly field strength with minimum achievable rise/fall time.
- e) Immediately after a guard time of  $t_{\rm PL}$  (as specified in ISO/IEC 14443-4:2018/Amd 1:2021, 7.5), send start of communication or SOF of the next block.
- f) Check that the PICC response is as expected.
- g) Repeat steps d) to f) until the Test PCD assembly field strength is  $H_{\text{max}}$ , using a smaller value for the last step increase if necessary, or until PLI<sub>CID</sub> is (00)b at step d).

#### Perform the following steps for single step down:

h) Adjust the RF power delivered by the signal generator to the Test PCD antenna to produce the PICC maximum field strength  $H_{\text{max}}$  as measured by the calibration coil.